

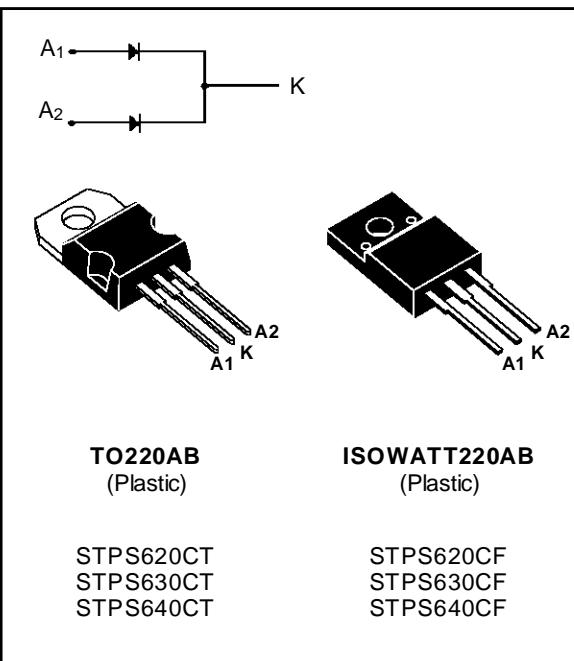
POWER SCHOTTKY RECTIFIER

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- EXTREMELY FAST SWITCHING
- LOW FORWARD VOLTAGE DROP
- HIGH AVALANCHE CAPABILITY
- LOW THERMAL RESISTANCE
- INSULATED PACKAGE :
 - Insulating voltage = 2000V DC
 - Capacitance = 12pF

DESCRIPTION

Dual center tap schottky rectifier suited for switch-mode power supply and high frequency DC to DC converters.

Packaged in TO220AB and ISOWATT220AB, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter			Value	Unit
$I_{F(RMS)}$	RMS Forward Current		Per diode	10	A
$I_{F(AV)}$	Average Forward Current $\delta = 0.5$	TO220AB	$T_c = 135^\circ C$	3	A
		ISOWATT220AB	$T_c = 130^\circ C$	6	
I_{FSM}	Surge Non Repetitive Forward Current		$T_p = 10 \text{ ms}$ Sinusoidal	75	A
I_{RRM}	Peak Repetitive Reverse Current		$T_p = 2 \mu s$ $F = 1 \text{ KHz}$	1	A
T_{stg} T_j	Storage and Junction Temperature Range			- 65 to + 150 - 65 to + 150	$^\circ C$
dV/dt	Critical Rate of Rise of Reverse Voltage			1000	$V/\mu s$

Symbol	Parameter	STPS			Unit
		620CT 620CF	630CT 630CF	640CT 640CF	
V_{RRM}	Repetitive Peak Reverse Voltage	20	30	40	V

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THERMAL RESISTANCE

Symbol	Parameter			Value	Unit
$R_{TH(j-c)}$	Junction-case	TO220AB	Per diode total	5.5 3.0	$^{\circ}\text{C}/\text{W}$
		ISOWATT220AB	Per diode total	7.5 5.2	
$R_{TH(c)}$	Coupling	TO220AB		0.5	$^{\circ}\text{C}/\text{W}$
		ISOWATT220AB		3	

When the diodes 1 and 2 are used simultaneously :

$$\Delta T_J(\text{diode 1}) = P(\text{diode 1}) \times R_{TH}(\text{Per diode}) + P(\text{diode 2}) \times R_{TH(c)}$$

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS PER DIODE

Symbol	Tests Conditions		Min.	Typ.	Max.	Unit
I_R *	$T_j = 25^{\circ}\text{C}$	$V_R = V_{RRM}$			100	μA
	$T_j = 125^{\circ}\text{C}$				10	mA
V_F **	$T_j = 125^{\circ}\text{C}$	$I_F = 6 \text{ A}$			0.72	V
	$T_j = 125^{\circ}\text{C}$	$I_F = 3 \text{ A}$			0.57	
	$T_j = 25^{\circ}\text{C}$	$I_F = 6 \text{ A}$			0.84	

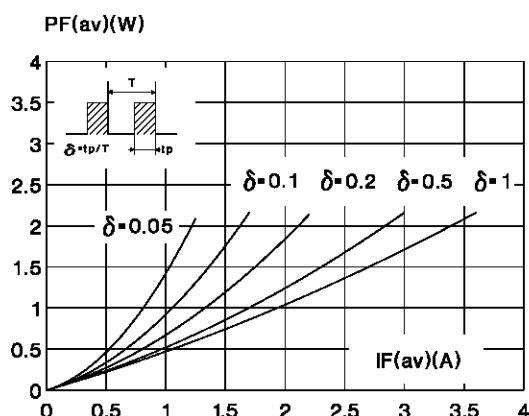
Pulse test : * $t_p = 5 \text{ ms}$, duty cycle < 2 %

** $t_p = 380 \text{ } \mu\text{s}$, duty cycle < 2%

To evaluate the conduction losses use the following equation :

$$P = 0.42 \times I_{F(AV)} + 0.050 I_{F}^2(\text{RMS})$$

Fig. 1 : Average forward power dissipation versus average forward current. (Per diode)



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Fig. 2 : Average current versus ambient temperature.
(duty cycle : 0.5) (Per diode) (TO220AB)

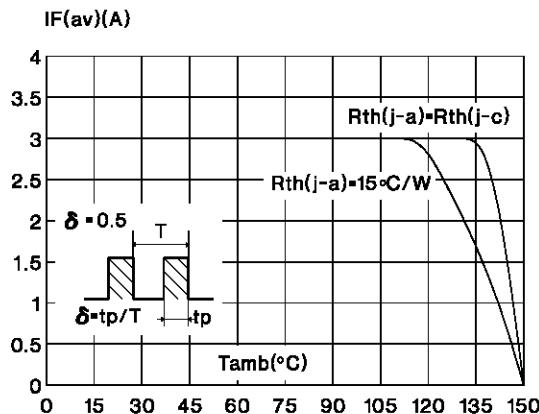


Fig. 4 : Non repetitive surge peak forward current versus overload duration.
(Maximum values) (Per diode) (TO220AB)

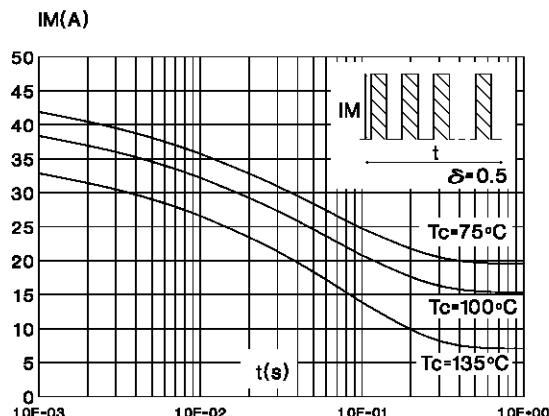


Fig. 6 : Relative variation of thermal transient impedance junction to case versus pulse duration.
(TO220AB)

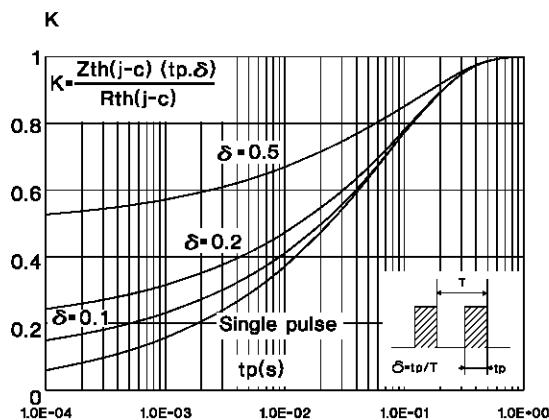


Fig. 3 : Average current versus ambient temperature.
(duty cycle : 0.5) (Per diode) (ISOWATT220AB)

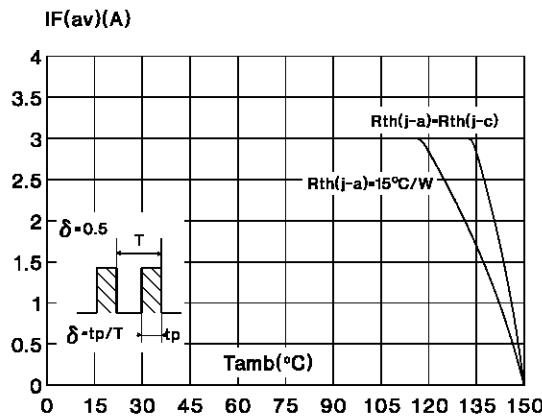


Fig. 5 : Non repetitive surge peak forward current versus overload duration.
(Maximum values) (Per diode) (ISOWATT220AB)

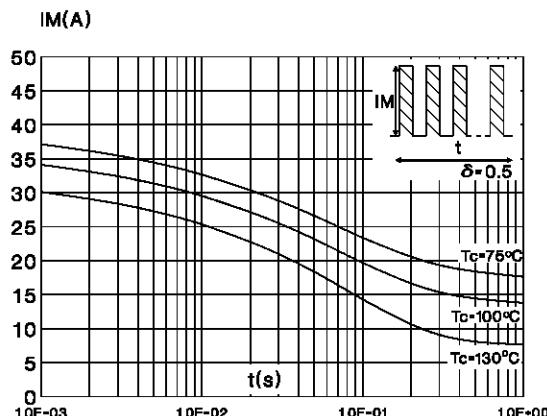
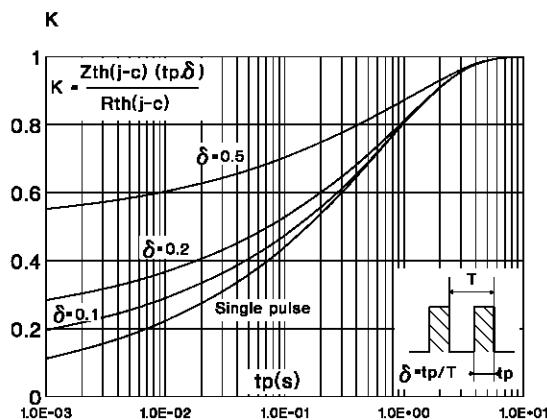


Fig. 7 : Relative variation of thermal transient impedance junction to case versus pulse duration.
(ISOWATT220AB)



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Fig. 8 : Reverse leakage current versus reverse voltage applied. (Typical values) (Per diode)

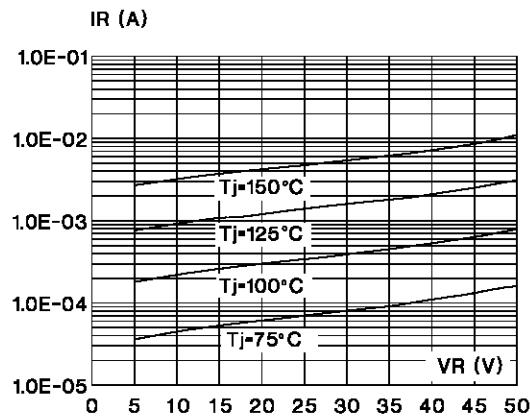


Fig. 9 : Junction capacitance versus reverse voltage applied (Typical values) (Per diode)

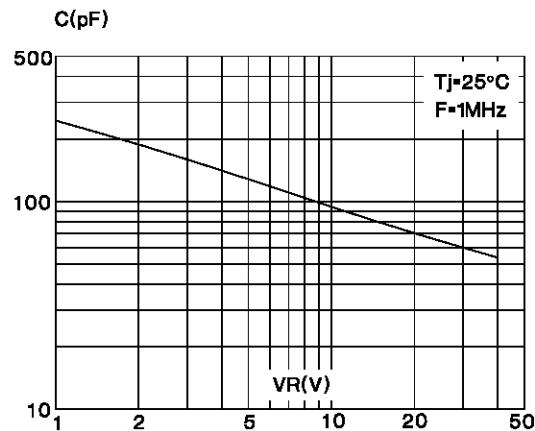
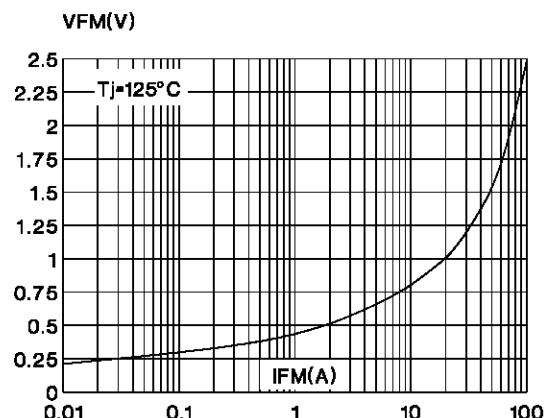
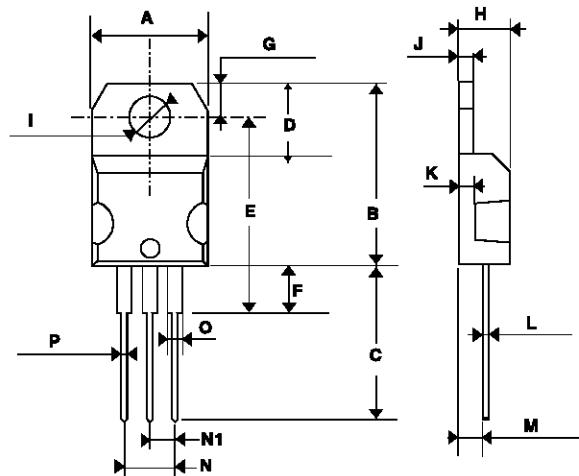


Fig. 10 : Forward voltage drop versus forward current. (Maximum values) (Per diode)



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PACKAGE MECHANICAL DATA TO220AB (JEDEC outline)



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	10.0	10.4	0.393	0.409
B	15.2	15.9	0.598	0.626
C	13	14	0.511	0.551
D	6.2	6.6	0.244	0.260
E	16.4 typ.		0.645 typ.	
F	3.5	4.2	0.137	0.165
G	2.65	2.95	0.104	0.116
H	4.4	4.6	0.173	0.181
I	3.75	3.85	0.147	0.151
J	1.23	1.32	0.048	0.051
K	1.27 typ.		0.050 typ.	
L	0.49	0.70	0.019	0.027
M	2.4	2.72	0.094	0.107
N	4.95	5.15	0.194	0.203
N1	2.40	2.70	0.094	0.106
O	1.14	1.70	0.044	0.067
P	0.61	0.88	0.024	0.034

Cooling method : C

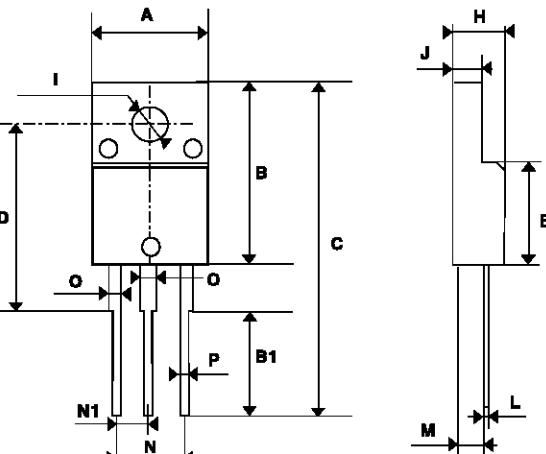
Marking : Type number

Weight : 2 g

Recommended torque value : 0.55m.N

Maximum torque value : 0.7m.N

PACKAGE MECHANICAL DATA ISOWATT220AB (JEDEC outline)



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	10	10.4	0.393	0.409
B	15.9	16.4	0.626	0.645
B1	9.8	10.6	0.385	0.417
C	28.6	30.6	1.126	1.204
D	16 typ		0.630 typ	
E	9	9.3	0.354	0.366
H	4.4	4.6	0.173	0.181
I	3	3.2	0.118	0.126
J	2.5	2.7	0.098	0.106
L	0.4	0.7	0.015	0.027
M	2.5	2.75	0.098	0.108
N	4.95	5.2	0.195	0.204
N1	2.4	2.7	0.094	0.106
O	1.15	1.7	0.045	0.067
P	0.75	1	0.030	0.039

Cooling method : C

Marking : Type number

Weight : 2.1 g

Recommended torque value : 0.55m.N

Maximum torque value : 0.70m.N

Electrical isolation : 2000V DC

Capacitance : 12pF

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